

Abstract Submitted  
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**Barium Hexaferrite Thick Films Made by Liquid Phase Epitaxy Reflow Method** ALAAEDEEN ABUZIR, University of Idaho, YANKO KRANOV TEAM, T. PRAKASH TEAM, D. MCILROY TEAM, W. J. YEH TEAM — In this work, we report on the growing of  $\text{BaFe}_{12}\text{O}_{19}$  (or BaM) thick films on (0001) sapphire  $\text{Al}_2\text{O}_3$  substrate. Our goal is to fabricate barium ferrite thick films which can be self-biased for circulator application. We have modified the liquid phase epitaxy (LPE) method by conducting the experiment in vacuum. A small chunk piece of the melt weighing about 0.035 g was placed on 1cm x 1cm  $\text{Al}_2\text{O}_3$  substrate and remelted at  $1200^\circ\text{C}$  for one hour. The thickness of our thick films grown by this reflow method range from 300 to 550  $\mu\text{m}$ . The coercivities of the thick films in the perpendicular direction were about 100Oe.

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